

T6C25

COLUMN AND ROW DRIVER FOR A DOT MATRIX LCD

The T6C25 is a 160-channel-output column and row driver for an STN dot matrix LCD.

The T6C25 features a 42-V LCD drive voltage and an 8-MHz maximum operating frequency. The T6C25 is able to drive LCD panels with a duty ratio of up to 1/480.

FEATURES

- Display duty application : to 1/480
- LCD drive signal : 160
- Data transfer : Column : 4/8-bit bidirectional
Row : Single/Dual bidirectional
- Operating frequency : 8MHz
- LCD drive voltage : 14 to 42V
- Power supply voltage : 2.7 to 5.5V
- Operating temperature : -20 to 75°C
- LCD drive output resistance : 1.3k Ω (max) (20V, 1/13 bias)
- Display-off function : When /DSPOF is L, all LCD drive outputs (O1 to O160) remain at the V₅ level.
- Low power consumption : Cascade connection and auto enable transfer functions are available.
- EI/LP input : EI/LP Input enables LSI operation.
Connect EIO 1/2 from the 1st LSI to L.

Unit: mm

T6C25	LEAD PITCH	
	IN	OUT
(UAM)	0.8	0.18
(SBM, 4NS)	0.8	0.23

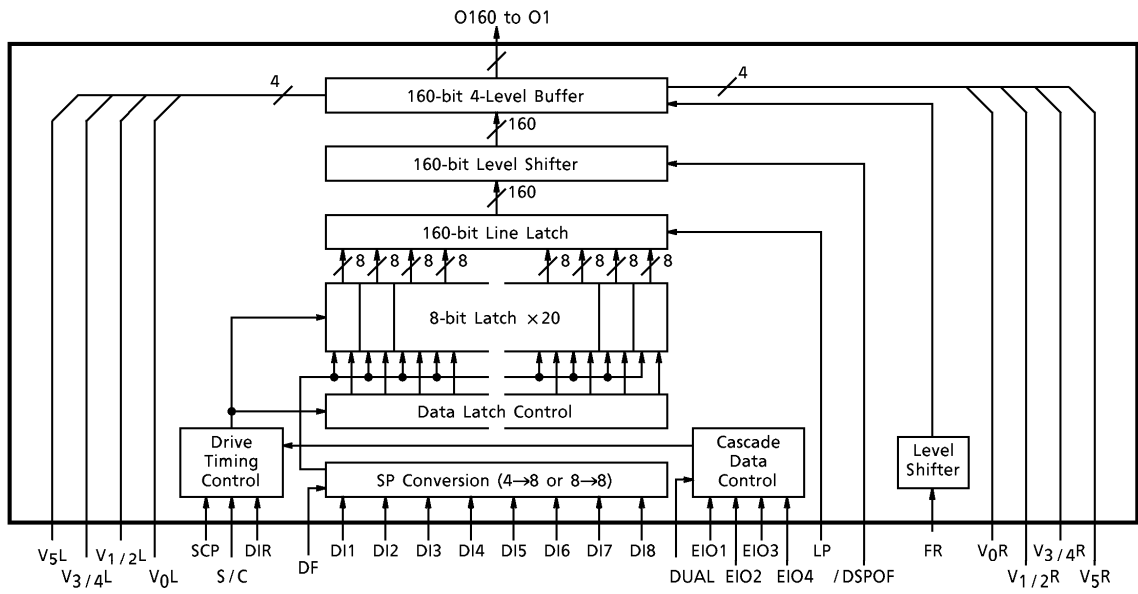
Please contact Toshiba or an authorized Toshiba dealer for information on package dimensions.

TCP (Tape Carrier Package)

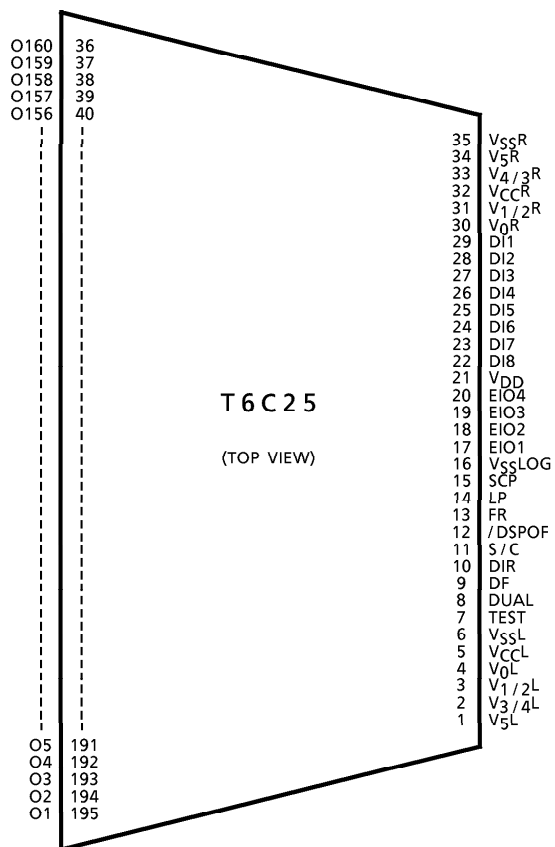
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BLOCK DIAGRAM



PIN ASSIGNMENT



* The above diagram shows the pin configuration of the LSI Chip, not that of the tape carrier package.

PIN FUNCTIONS

PIN NAME	I/O	FUNCTIONS	LEVEL
O1 to O160	Output	Output for LCD drive signal	V ₀ to V ₅
EIO1 to EIO4	I/O	Input/output for enable signal DIR selects In or Out. Connect EIO (IN) of 1st LSI to L. For a cascade connection, connect EIO (OUT) to EIO (IN) of next LSI.	V _{DD} to V _{SS}
DI1 to DI8	Input	(Column mode) Input for data signal	
		(Row mode) Fix to H or L	
DIR	Input	(Direction) Input for data flow direction select,	
/DSPOF	Input	(Display Off) /DSPOF = L : Display-off mode, (O1 to O160) remain at the V ₅ level. /DSPOF = H : Display-on mode, (O1 to O160) are operational.	
DF	Input	(Column mode) Input for data bit select	
		(Row mode) Fix to H or L	
DUAL	Input	(Column mode) Fix to H or L	
		(Row mode) Input for dual/single select	
LP	Input	(Column mode) Display data is latched on the falling edge of LP. When EIO (IN) = L, setting $\overline{\text{SCP}} \cdot \text{LP} = \text{H}$ enables the 1st LSI.	
		(Row mode) Input for shift clock pulse	
FR	Input	(Frame) Input for frame signal	
SCP	Input	(Column mode) Input for shift clock pulse	
		(Row mode) Fix to H or L	
TEST	Input	(TEST) Fix to L	
S/C	Input	Input for mode select : H = Column mode, L = Row mode	

PIN NAME	I/O	FUNCTIONS	LEVEL
V _{DD}	—	Power supply for internal logic (+5.0V)	—
V _{SS}	—	Power supply for internal logic (0V)	
V _{5L·R}	—	Power supply for LCD drive circuit	
V _{3/4L·R}	—	Power supply for LCD drive circuit	
V _{2/1L·R}	—	Power supply for LCD drive circuit	
V _{0L·R}	—	Power supply for LCD drive circuit	
V _{CC·L·R}	—	Power supply for LCD drive circuit	

RELATION BETWEEN FR, DATA INPUT AND OUTPUT LEVEL

FR	DATA INPUT	/DSPOF	OUTPUT LEVEL (Column Mode)	OUTPUT LEVEL (Row Mode)
L	L	H	V ₃	V ₄
L	H	H	V ₅	V ₀
H	L	H	V ₂	V ₁
H	H	H	V ₀	V ₅
*	*	L	V ₅	V ₅

* Don't care

DATA INPUT FORMAT

Column mode

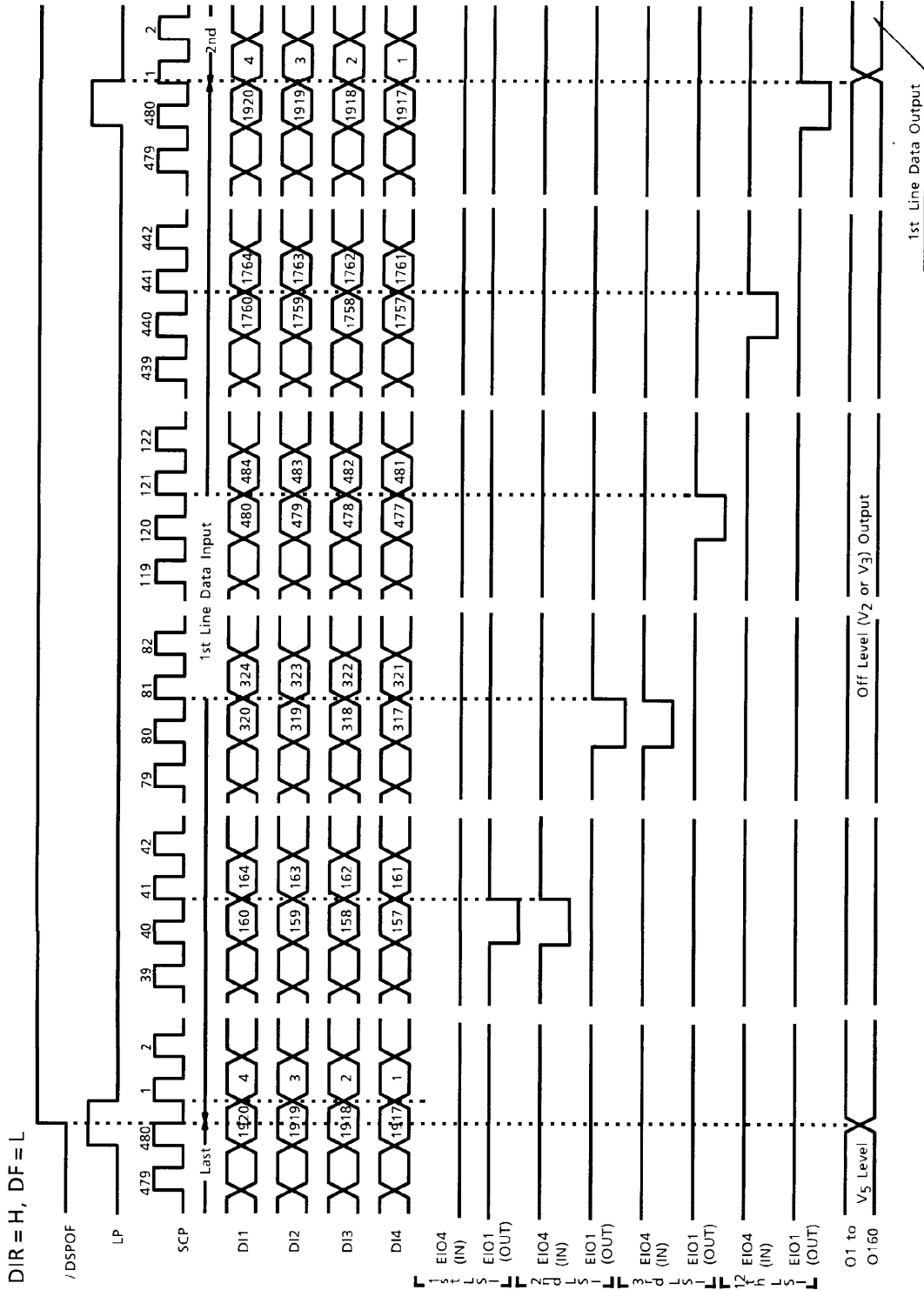
DIR	DF	BIT MODE	ENABLE PIN		(*1)	INPUT DATA LINE AND OUTPUT BUFFERS							
			EIO1	EIO4		DI1	DI2	DI3	DI4	DI5	DI6	DI7	DI8
H	L	4-BIT	OUT	IN	L	O160	O159	O158	O157	—	—	—	—
					F	O4	O3	O2	O1	—	—	—	—
L			IN	OUT	L	O1	O2	O3	O4	—	—	—	—
					F	O157	O158	O159	O160	—	—	—	—
H	H	8-BIT	OUT	IN	L	O160	O159	O158	O157	O156	O155	O154	O153
					F	O8	O7	O6	O5	O4	O3	O2	O1
L			IN	OUT	L	O1	O2	O3	O4	O5	O6	O7	O8
					F	O153	O154	O155	O156	O157	O158	O159	O160

(*1) L : Last Data
F : First Data

Row mode

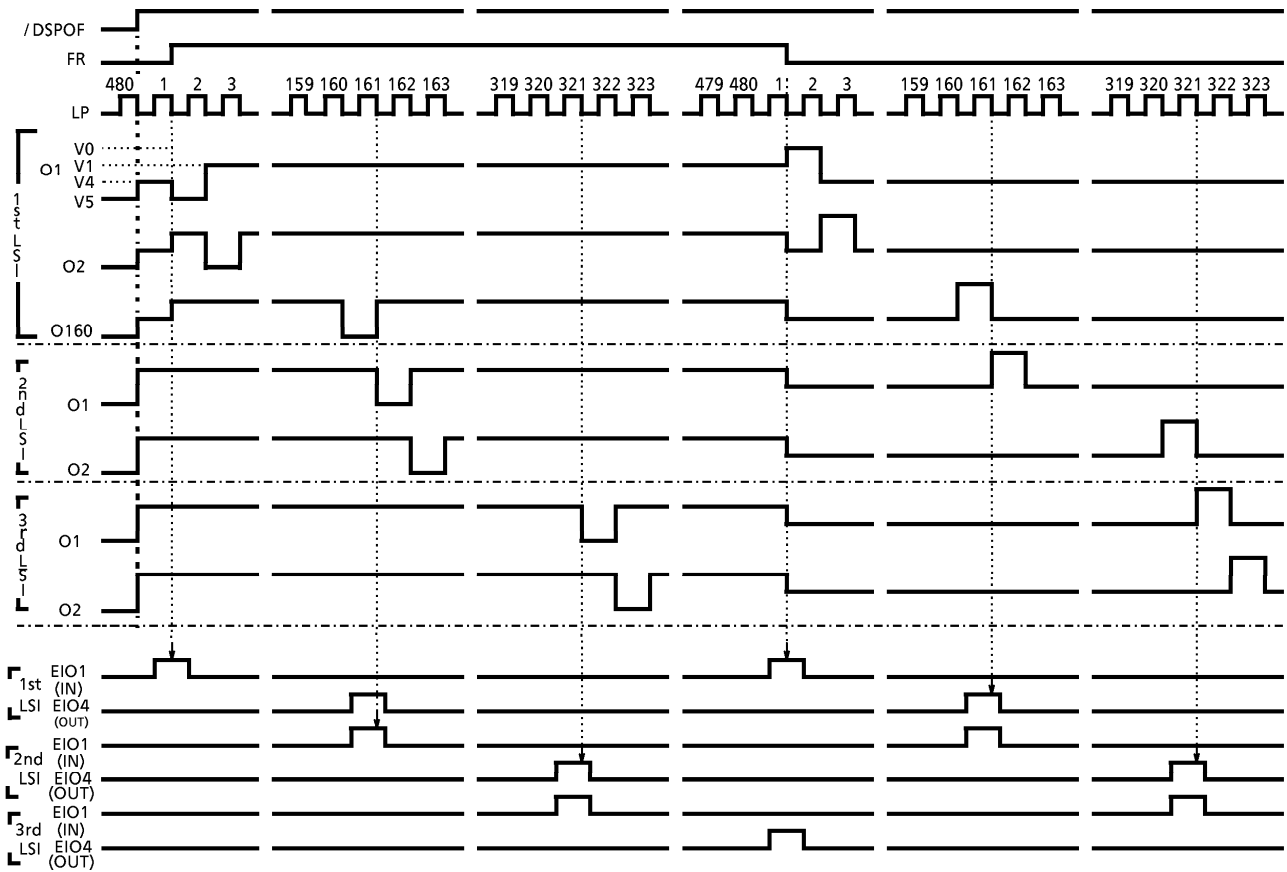
DUAL	DIR	DATA FLOW	DATA INPUT TERMINALS			
			EIO1	EIO2	EIO3	EIO4
L	L	O160→O1	OUT	—	—	IN
L	H	O1→O160	IN	—	—	OUT
H	L	O160→O81 O80→O1	OUT	IN	OUT	IN
H	H	O1→O80 O81→O160	IN	OUT	IN	OUT

TIMING DIAGRAM (Column mode)



TIMING DIAGRAM (Row mode)

DIR = H, DUAL = L



ABSOLUTE MAXIMUM RATINGS(Ensure that the following conditions are maintained, $V_{CC} \geq V_0 \geq V_2 \geq V_3 \geq V_5 \geq V_{SS}$)

ITEM	SYMBOL	PIN NAME	RATING	UNIT
Supply Voltage ①	V_{DD}	V_{DD}	-0.3 to 7.0	V
Supply Voltage ②	V_{CC}	V_{CC}/R	-0.3 to 45.0	V
Supply Voltage ③	V_0, V_2	$V_{0L}/R, V_{2L}/R$	-0.3 to $V_{CC} + 0.3$	V
Supply Voltage ④	V_3, V_5	$V_{3L}/R, V_{5L}/R$	-0.3 to 7.0	V
Input Voltage	V_{IN}	(*2)	-0.3 to $V_{DD} + 0.3$	V
Operating Temperature	T_{opr}	—	-20 to 75	°C
Storage Temperature	T_{stg}	—	-40 to 125	°C

(*2) SCP, FR, LP, DIR, DF, DUAL, S/C, EIO1 to 4, DI1 to 8, /DSPOF, TEST

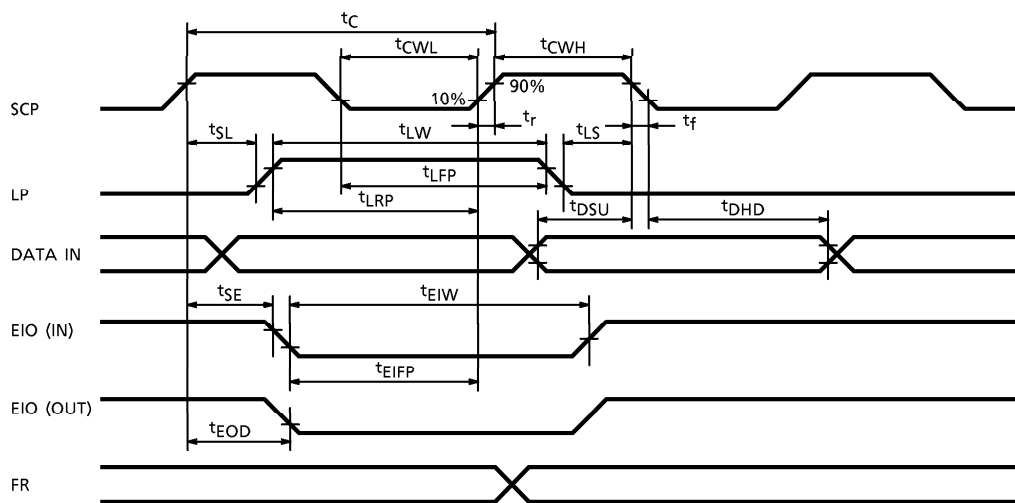
ELECTRICAL CHARACTERISTICS**DC CHARACTERISTICS**(Unless otherwise noted, $V_{SS} = 0V$, $V_{DD} = 2.7$ to $5.5V$, $T_a = -20$ to $75^\circ C$)

ITEM	SYMBOL	TEST CIR-CUIT	TEST CONDITIONS	MIN	TYP.	MAX	UNIT	PIN NAME		
Supply Voltage 1	V_{DD}	—	—	2.7	5.0	5.5	V	V_{DD}		
Supply Voltage 2	V_{CC}	—	—	14	—	42		V_{CC}/R		
Input Voltage	H Level	V_{IH}	(*2)	0.8 V_{DD}	—	V_{DD}	V	SCP, FR, LP, DIR, DF, DUAL, S/C, EIO1 to 4, DI1 to 8, /DSPOF, TEST		
	L Level	V_{IL}		0	—	0.2 V_{DD}				
Output Voltage	H Level	V_{OH}	$I_{OH} = -0.4mA$	V_{DD} -0.5	—	V_{DD}			V	EIO1 to 4
	L Level	V_{OL}	$I_{OL} = 0.4mA$	0	—	0.5				
Output Resistance	H Level	R_{OH}	$V_{OUT} = V_0 - 0.5V$ (*3)	—	0.6	1.3	k Ω	O1 to 160		
	M Level	R_{OM}	$V_{OUT} = V_2 \pm 0.5V$ (*3)	—	0.6	1.3				
			$V_{OUT} = V_3 \pm 0.5V$ (*3)	—	0.6	1.3				
	L Level	R_{OL}	$V_{OUT} = V_5 + 0.5V$ (*3)	—	0.6	1.3				
Current Consumption (*4)	I_{DD}	—	$V_{DD} = 5.5V$ $V_{CC} = 42V$ $f_{FR} = 40Hz$ $f_{scp} = 8.0MHz$ Input Data : every bit inverted $V_{IH} = 5.5V, V_{IL} = 0V$	—	—	3.0	mA	V_{DD}		

(*3) $V_{CC} = 20V$, 1/13 bias

(*4) Current consumption while the internal data receiver is operating.

AC ELECTRICAL CHARACTERISTICS (Column mode)



TEST CONDITIONS (1) ($V_{SS} = 0V$, $V_{DD} = 4.5$ to $5.5V$, $V_{CC} = 14$ to $42V$, $T_a = -20$ to $75^\circ C$)

ITEM	SYMBOL	TEST CONDITIONS	MIN	MAX	UNIT
Clock Cycle	t_c	—	125	—	ns
SCP Pulse Width	t_{CWH}, t_{CWL}	—	50	—	ns
Data Set-up Time	t_{DSU}	—	50	—	ns
Data Hold Time	t_{DHD}	—	50	—	ns
SCP Rise/Fall Time	t_r, t_f	—	—	(*5)	ns
LP Rise Time	t_{LRP}	—	50	—	ns
LP Fall Time	t_{LFP}	—	50	—	ns
LP Pulse Width	t_{LW}	—	45	—	ns
SCP-to-LP Delay Time	t_{SL}	—	40	—	ns
LP-to-SCP Delay Time	t_{LS}	—	40	—	ns
EIO-In Fall Time	t_{EIOIN}	—	40	—	ns
EIO-In Pulse Width	t_{EIOIN}	—	40	—	ns
SCP-to-EIO Delay Time	t_{SE}	—	20	—	ns
EIO-Out Delay Time	t_{EIOOUT}	(*6)	—	80	ns

(*5) $t_r, t_f \leq (t_c - t_{CWH} - t_{CWL}) / 2$ and $t_r, t_f \leq 50ns$

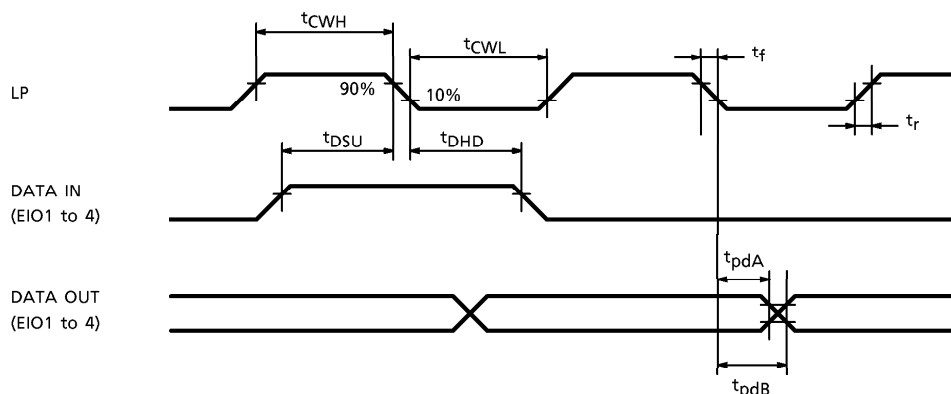
(*6) $C_L = 30pF$

TEST CONDITIONS (2) ($V_{SS} = 0V$, $V_{DD} = 2.7$ to $4.5V$, $V_{CC} = 14$ to $42V$, $T_a = -20$ to $75^{\circ}C$)

ITEM	SYMBOL	TEST CONDITIONS	MIN	MAX	UNIT
Clock Cycle	t_C	—	500	—	ns
SCP Pulse Width	t_{CWH} , t_{CWL}	—	240	—	ns
Data Set-up Time	t_{DSU}	—	240	—	ns
Data Hold Time	t_{DHD}	—	240	—	ns
SCP Rise / Fall Time	t_r , t_f	—	—	(*5)	ns
LP Rise Time	t_{LRP}	—	240	—	ns
LP Fall Time	t_{LFP}	—	240	—	ns
LP Pulse Width	t_{LW}	—	240	—	ns
SCP-to-LP Delay Time	t_{SL}	—	50	—	ns
LP-to-SCP Delay Time	t_{LS}	—	100	—	ns
EIO-In Fall Time	t_{EIFP}	—	240	—	ns
EIO-In Pulse Width	t_{EIW}	—	240	—	ns
SCP-to-EIO Delay Time	t_{SE}	—	50	—	ns
EIO-Out Delay Time	t_{EOD}	(*6)	—	260	ns

(*5) t_r , $t_f \leq (t_C - t_{CWH} - t_{CWL}) / 2$ and t_r , $t_f \leq 50ns$ (*6) $C_L = 30pF$

AC ELECTRICAL CHARACTERISTICS (Row mode)



TEST CONDITIONS (1) ($V_{SS} = 0V$, $V_{DD} = 4.5$ to $5.5V$, $V_{CC} = 14$ to $42V$, $T_a = -20$ to $75^\circ C$)

ITEM	SYMBOL	TEST CONDITIONS	MIN	MAX	UNIT
LP Pulse Width H	t_{CWH}	LP	30	—	ns
LP Pulse Width L	t_{CWL}	LP	195	—	ns
SCP Rise / Fall Time	t_r, t_f	LP, FR, EIO1 to 4	—	20	ns
Data Set-up Time	t_{DSU}	EIO1 to 4	80	—	ns
Data Hold Time	t_{DHD}	EIO1 to 4	0	—	ns
EIO-Out Delay Time A (*7)	t_{pdA}	EIO1 to 4	5	—	ns
EIO-Out Delay Time B (*7)	t_{pdB}	EIO1 to 4	—	150	ns

TEST CONDITIONS (2) ($V_{SS} = 0V$, $V_{DD} = 2.7$ to $5.5V$, $V_{CC} = 14$ to $42V$, $T_a = -20$ to $75^\circ C$)

ITEM	SYMBOL	TEST CONDITIONS	MIN	MAX	UNIT
LP Pulse Width H	t_{CWH}	LP	100	—	ns
LP Pulse Width L	t_{CWL}	LP	400	—	ns
SCP Rise / Fall Time	t_r, t_f	LP, FR, EIO1 to 4	—	20	ns
Data Set-up Time	t_{DSU}	EIO1 to 4	130	—	ns
Data Hold Time	t_{DHD}	EIO1 to 4	0	—	ns
EIO-Out Delay Time A (*7)	t_{pdA}	EIO1 to 4	5	—	ns
EIO-Out Delay Time B (*7)	t_{pdB}	EIO1 to 4	—	400	ns

(*7) $C_L = 30pF$

(Note) Insert the bypass capacitor ($0.1\mu F$) between V_{DD} and V_{SS} to decrease power supply noise.

Place the bypass capacitor as close to the LSI as possible.